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TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT process)

2SC5172

Switching Regulator and High-Voltage Switching Applications

High-Speed DC-DC Converter Applications

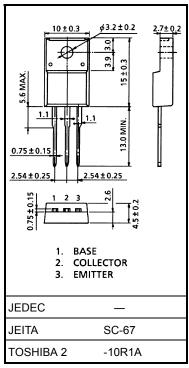
• Excellent switching times: $t_r = 0.5 \ \mu s \ (max)$,

 $t_f = 0.3 \ \mu s \ (max) \ at \ I_C = 2 \ A$

• High collector breakdown voltage: $V_{CEO} = 400 \text{ V}$

Maximum Ratings (Tc = 25°C)

Characteristics Sy		mbol	Rating	Unit	
Collector-base voltage		V _{CBO}	600	V	
Collector-emitter voltage		V _{CEO}	400	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC I	С	5	А	
	Pulse I	_{CP} 7		~	
Base current		Ι _Β	2 A		
Collector power dissipation	Ta = 25°C	D-	2.0	W	
	Tc = 25°C	P _C	25		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Electrical Characteristics (Tc = 25°C)

Characteristics Sy		mbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 500 V, I _E = 0		<u> </u>		μA
Emitter cut-off current		I _{EBO}	V _{EB} = 7 V, I _C = 0		— 100		nA
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _E = 0	600	—	— V	
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	400	_	-V	
DC current gain		hFE (1)	V _{CE} = 5 V, I _C = 1 mA	13	_	-	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.5 A	20	— 65		
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 2 A, I _B = 0.25 A	—	<u> </u>	0	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 2 A, I _B = 0.25 A		— 1.	3	V
Switching time	Rise time	t _r	20 µs Input B1 C m m m m m m m m m m m m m m m m m m m	_	— 0 .	5	
	Storage time	t _{stg}		_	— 2.	0	μs
	Fall time	t _f	I _{B1} = 0.25 A, I _{B2} = -0.5 A, duty cycle < 1%	_	— 0.	3	

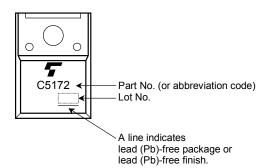
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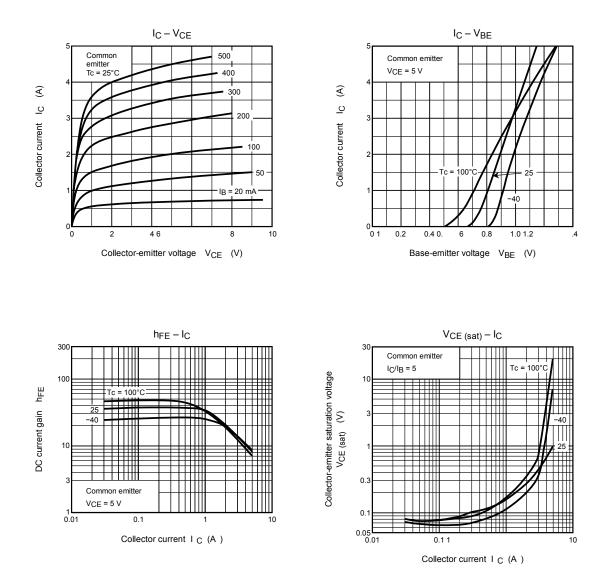
Unit: mm

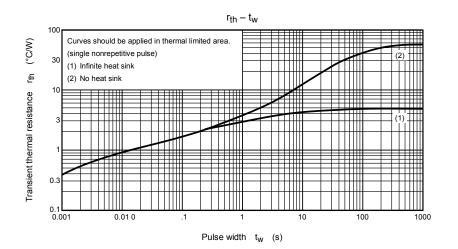
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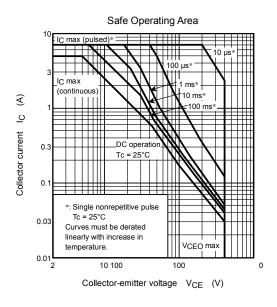
Marking



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